**Product data sheet** 

#### 1. **Product profile**

## 1.1 General description

Planar passivated high commutation three quadrant triac in a SOT428 surface-mountable plastic package. This "series D" triac balances the requirements of commutation performance and gate sensitivity. The "very sensitive" "series D" is intended for interfacing with low power drivers including microcontrollers.

### 1.2 Features and benefits

- 3Q technology for improved noise immunity
- Direct interfacing with low power drivers and microcontrollers
- Good immunity to false turn-on by dV/dt
- High commutation capability with very sensitive gate
- High voltage capability
- Planar passivated for voltage ruggedness and reliability
- Surface-mountable package
- Triggering in three quadrants only

### 1.3 Applications

Electronic thermostats

General purpose motor controls

### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{DRM}$	repetitive peak off-state voltage		-	-	600	V
I <sub>TSM</sub>	non-repetitive peak on-state current	full sine wave; $T_{j(init)} = 25 \text{ °C}$ ; $t_p = 20 \text{ ms}$ ; see <u>Figure 4</u> ; see <u>Figure 5</u>	-	-	65	Α
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; T <sub>mb</sub> ≤ 102 °C; see <u>Figure 1</u> ; see <u>Figure 2</u> ; see <u>Figure 3</u>	-	-	8	Α



Table 1. Quick reference data ...continued

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
٥.	gate trigger current	$V_D$ = 12 V; $I_T$ = 0.1 A; T2+ G+; $T_j$ = 25 °C; see <u>Figure 7</u>	-	-	5	mA
		$V_D$ = 12 V; $I_T$ = 0.1 A; T2+ G-; $T_j$ = 25 °C; see <u>Figure 7</u>	-	-	5	mA
		$V_D$ = 12 V; $I_T$ = 0.1 A; T2- G-; $T_j$ = 25 °C; see <u>Figure 7</u>	-	-	5	mA

# 2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1		N.1
2	T2	main terminal 2	mb	T2T1
3	G	gate		sym051
mb	T2	mounting base; main terminal 2	1 3	
			SOT428 (DPAK)	

# 3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BTA208S-600D	DPAK	plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)	SOT428

# 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DRM}$	repetitive peak off-state voltage	2	-	600	V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; T <sub>mb</sub> ≤ 102 °C; see <u>Figure 1</u> ; see <u>Figure 2</u> ; see <u>Figure 3</u>	-	8	Α
I <sub>TSM</sub>	non-repetitive peak on-state current	full sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 20 ms; see <u>Figure 4</u> ; see <u>Figure 5</u>	-	65	Α
		full sine wave; $T_{j(init)} = 25 ^{\circ}C$ ; $t_p = 16.7  ms$	-	72	Α
I <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; sine-wave pulse	-	21	$A^2s$
dI <sub>T</sub> /dt	rate of rise of on-state current	$I_T$ = 12 A; $I_G$ = 0.2 A; $dI_G/dt$ = 0.2 A/ $\mu$ s	-	100	A/µs
$I_{\text{GM}}$	peak gate current		-	2	Α
$V_{GM}$	peak gate voltage		-	5	V
$P_GM$	peak gate power		-	5	W
$P_{G(AV)}$	average gate power	over any 20 ms period	-	0.5	W
T <sub>stg</sub>	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C

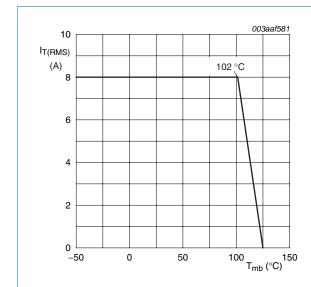
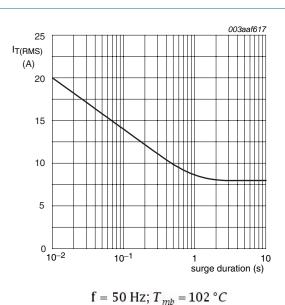


Fig 1. RMS on-state current as a function of heatsink temperature; maximum values



ig 2. RMS on-state current as a function of surge duration; maximum value

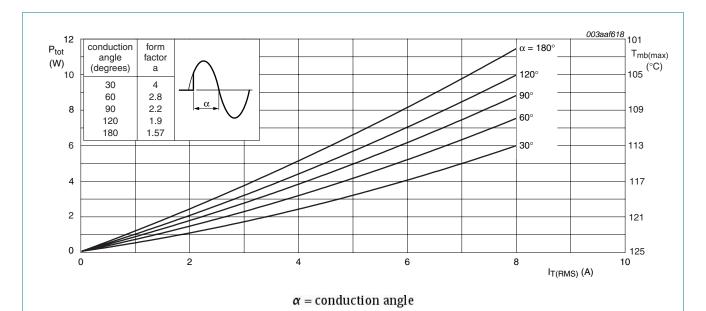


Fig 3. Total power dissipation as a function of RMS on-state current; maximum values

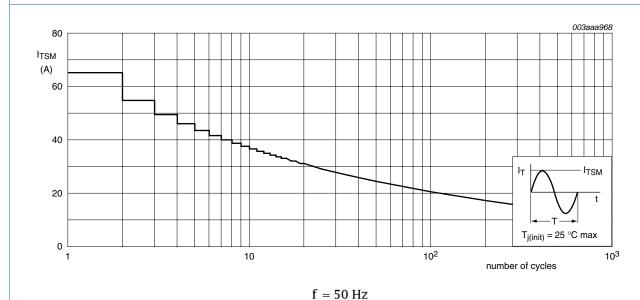
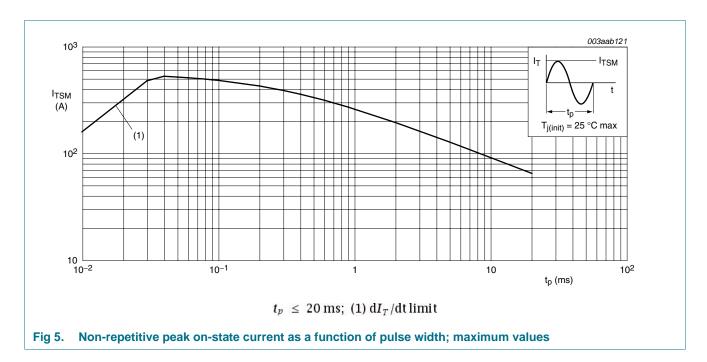


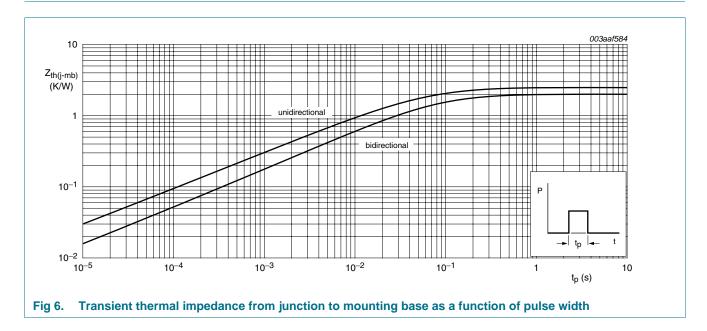
Fig 4. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values



## 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance	full cycle; see Figure 6	-	-	2	K/W
	from junction to mounting base	half cycle; see Figure 6	-	-	2.4	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient	in free air; printed circuit board (FR4) mounted	-	75	-	K/W



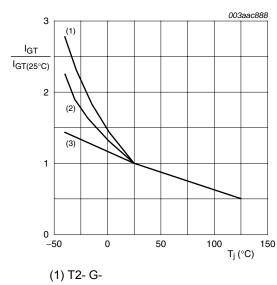
# 6. Characteristics

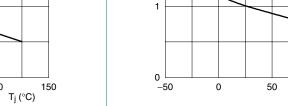
Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
I <sub>GT</sub>	gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T2+ G+;$ $T_j = 25 ^{\circ}\text{C}; \text{ see } \frac{\text{Figure } 7}{\text{C}}$	-	-	5	mA
		$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T2+ \text{ G-};$ $T_j = 25 ^{\circ}\text{C}; \text{ see } \frac{\text{Figure } 7}{\text{ Composition}}$	-	-	5	mA
		$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T2- \text{G-};$ $T_j = 25 ^{\circ}\text{C}; \text{ see } \frac{\text{Figure 7}}{\text{C}}$	-	-	5	mA
l <sub>L</sub>	latching current	$V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; T2+ G+;$ $T_j = 25 ^{\circ}\text{C}; \text{ see } \frac{\text{Figure 8}}{\text{C}}$	-	-	15	mA
		$V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; T2+ G-;$ $T_j = 25 ^{\circ}\text{C}; \text{ see } \frac{\text{Figure 8}}{\text{C}}$	-	-	25	mA
		$V_D = 12 \text{ V; } I_G = 0.1 \text{ A; T2- G-;}$ $T_j = 25 ^{\circ}\text{C; see } \frac{\text{Figure 8}}{\text{C}}$	-	-	25	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; see <u>Figure 9</u>	-	-	15	mΑ
$V_{T}$	on-state voltage	I <sub>T</sub> = 10 A; T <sub>j</sub> = 25 °C; see <u>Figure 10</u>	-	-	1.65	V
V <sub>GT</sub>	gate trigger voltage	$V_D$ = 12 V; $I_T$ = 0.1 A; $T_j$ = 25 °C; see <u>Figure 11</u>	-	-	1.5	V
		$V_D = 400 \text{ V}; I_T = 0.1 \text{ A}; T_j = 125 ^{\circ}\text{C};$ see <u>Figure 11</u>	0.25	-	-	V
I <sub>D</sub>	off-state current	V <sub>D</sub> = 600 V; T <sub>j</sub> = 125 °C	-	-	0.5	mΑ
Dynamic ch	naracteristics					
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 402 V; $T_j$ = 110 °C; exponential waveform; gate open circuit	20	-	-	V/µs
dl <sub>com</sub> /dt	rate of change of commutating current	$V_D$ = 400 V; $T_j$ = 125 °C; $I_{T(RMS)}$ = 8 A; $dV_{com}/dt$ = 0.1 V/ $\mu$ s; gate open circuit	6	-	-	A/ms
		$V_D$ = 400 V; $T_j$ = 125 °C; $I_{T(RMS)}$ = 8 A; $dV_{com}/dt$ = 10 V/ $\mu$ s; gate open circuit; see Figure 12	2	-	-	A/ms

T<sub>i</sub> (°C)

(2) T2+ G-(3) T2+ G+ **3Q Hi-Com Triac** 





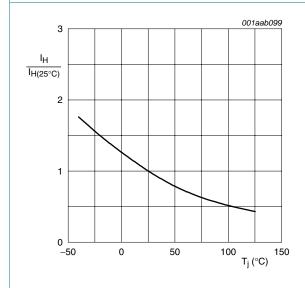
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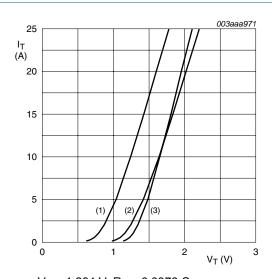
 $I_{\mathsf{L}}$ 

I<sub>L(25°C)</sub>

- Fig 7. Normalized gate trigger current as a function of junction temperature
- Fig 8. Normalized latching current as a function of junction temperature



junction temperature



Normalized holding current as a function of

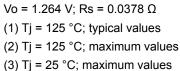


Fig 10. On-state current as a function of on-state voltage

Fig 9.

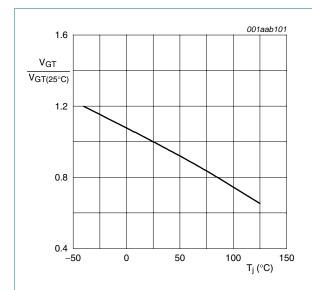


Fig 11. Normalized gate trigger voltage as a function of junction temperature

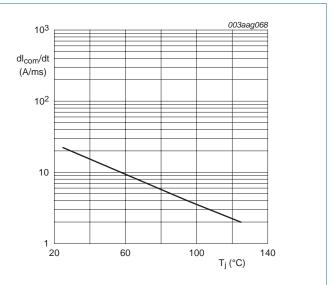


Fig 12. Rate of change of commutating current as a function of junction temperature; minimum values

# 7. Package outline

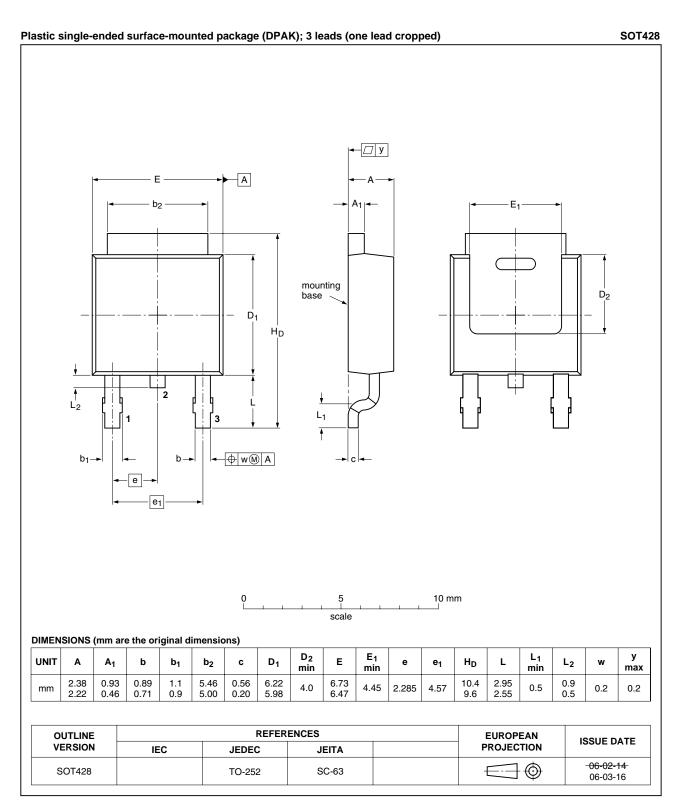


Fig 13. Package outline SOT428 (DPAK)

# 8. Revision history

## Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BTA208S-600D v.5	20110413	Product data sheet	-	BTA208S_SERIES_D_E_F_4
Modifications:	guidelines	s of NXP Semiconductors	S.	comply with the new identity
	•	•		name where appropriate.
	• •	nber BTA208S-600D sepa _SERIES_D_E_F_4.	arated from data s	heet
BTA208S_SERIES_D_E_F_4	20020301	Product specification	-	BTA208S_SERIES_D_E_F_3

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#### 9.1 Data sheet status

Document status [1] [2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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